Amplifier Transistors

NPN Silicon

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	6429DW1T1	Unit
Collector - Emitter Voltage	V_{CEO}	45	Vdc
Collector - Base Voltage	V _{CBO}	55	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ic	200	mAdc

THERMAL CHARACTERISTICS

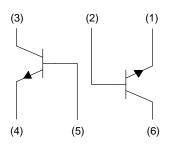
Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$	P _D	150	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

 Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended foot print.

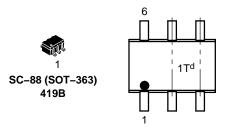


ON Semiconductor®

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MARKING DIAGRAM



1T = Specific Device Code

d = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MBT6429DW1T1	SC-88	3000 / Tape & Reel
MBT6429DW1T1G	SC-88 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0)	V _{(BR)CEO}	45	_	Vdc
Collector – Base Breakdown Voltage (I _C = 0.1 mAdc, I _E = 0)	V _{(BR)CBO}	55	_	Vdc
Collector Cutoff Current (V _{CE} = 30 Vdc)	I _{CES}	_	0.1	μAdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	I _{CBO}	_	0.01	μAdc
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ Vdc}, I_{C} = 0)$	I _{EBO}	_	0.01	μAdc
ON CHARACTERISTICS		-		
DC Current Gain $ \begin{array}{l} (I_{C}=0.01 \text{ mAdc, } V_{CE}=5.0 \text{ Vdc}) \\ (I_{C}=0.1 \text{ mAdc, } V_{CE}=5.0 \text{ Vdc}) \\ (I_{C}=1.0 \text{ mAdc, } V_{CE}=5.0 \text{ Vdc}) \\ (I_{C}=10 \text{ mAdc, } V_{CE}=5.0 \text{ Vdc}) \\ (I_{C}=10 \text{ mAdc, } V_{CE}=5.0 \text{ Vdc}) \end{array} $	h _{FE}	500 500 500 500	- 1250 - -	_
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 0.5 \text{ mAdc}$) ($I_C = 100 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	V _{CE(sat)}	_ _	0.2 0.6	Vdc
Base – Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	0.56	0.66	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, f = 100 MHz)	f _T	100	700	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	3.0	pF
Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$)	C _{ibo}	_	8.0	pF

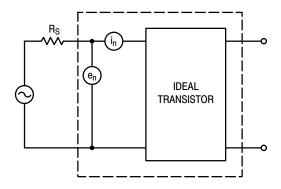
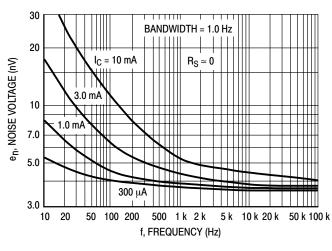


Figure 1. Transistor Noise Model

NOISE CHARACTERISTICS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

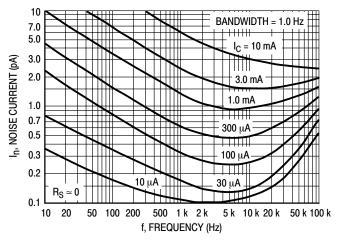
NOISE VOLTAGE



BANDWIDTH = 1.0 Hz 20 en, NOISE VOLTAGE (nV) $R_S \approx 0\,$ f = 10 Hz 10 100 Hz 1.0 kHz 5.0 3.0 0.01 0.02 0.05 0.1 0.2 0.5 2.0 5.0 10 IC, COLLECTOR CURRENT (mA)

Figure 2. Effects of Frequency

Figure 3. Effects of Collector Current



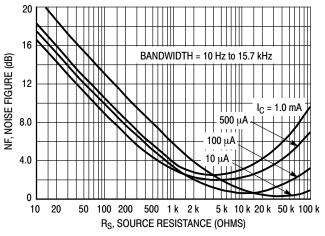
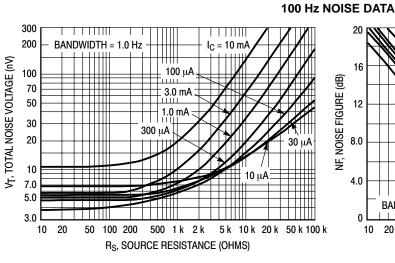


Figure 4. Noise Current

Figure 5. Wideband Noise Figure



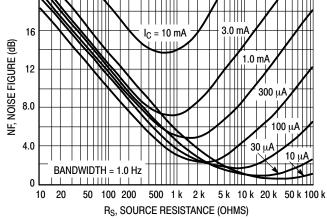


Figure 6. Total Noise Voltage

Figure 7. Noise Figure

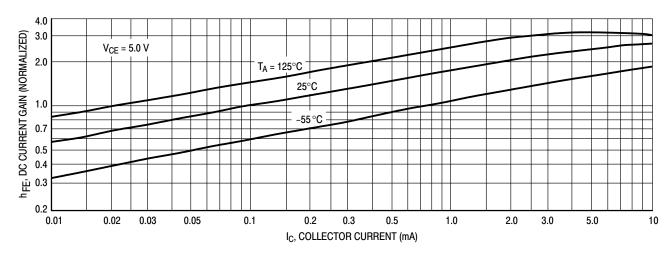


Figure 8. DC Current Gain

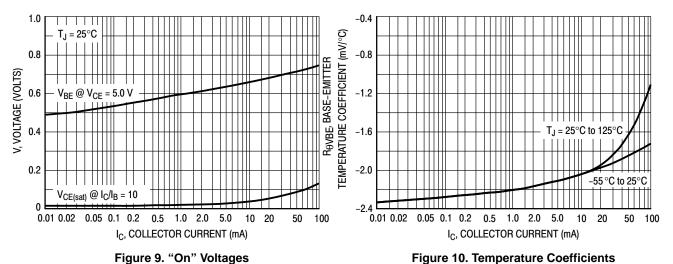


Figure 9. "On" Voltages

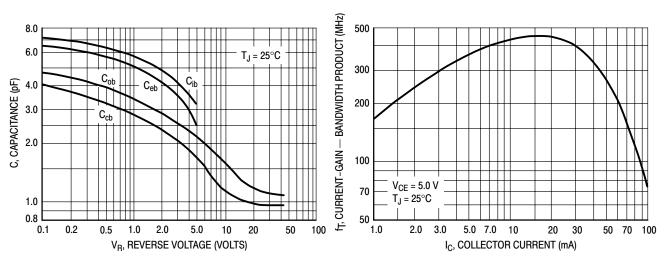


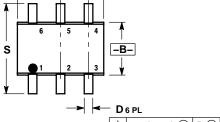
Figure 11. Capacitance

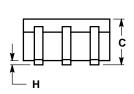
Figure 12. Current-Gain - Bandwidth Product

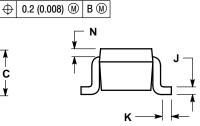
PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02 ISSUE 02U



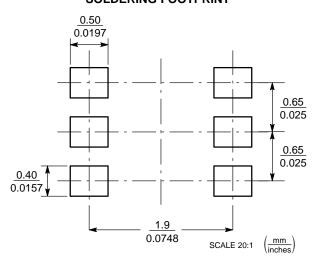




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008	0.008 REF		REF
S	0.079	0.087	2.00	2.20

SOLDERING FOOTPRINT*



SC-88/SC70-6/SOT-363

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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